

Silicon Hyperabrupt Varactor Diode Low Voltage / Low Series Resistance

Rev. V9

Features

- Low Series Resistance @ Low Tuning Voltages
- High Capacitance Ratio @ Low Tuning Voltages
- Surface Mount Plastic Packages: SC-79, SOD-323, SC-70 (3L) (other packages & configurations available)
- SPC Process for Superior C vs. V Repeatability
- Lead-Free Packages
- RoHS* Compliant

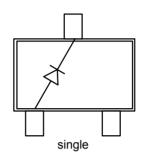
Description and Applications

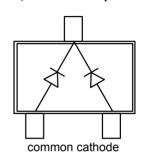
The MAVR-0013xx series is a highly repeatable, UHCVD / ion-implanted, hyperabrupt silicon tuning varactor. This series of varactors is designed for high capacitance ratio, and high Q for low battery voltage operation. It is efficient for wide band tuning and low phase noise application where the supply voltage is limited to 5 volts or less.

These cost effective surface mount packaged varactors are offered as singles in SC-79 and SOD-323 along with a common cathode version offered in the SC-70, 3 Lead. These diodes are offered with standard 100% matte Sn plating.

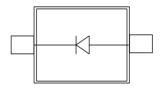
Configurations

Top View (SOT-23, SC70 3LD)





Top View (SOD-323, SC-79)



Ordering Information

Part #	Configuration	Package	Package Cp (pF)	Package Ls (nH)
MAVR-001320-12790T	Single	SC-79	0.10	0.6
MAVR-001330-12790T	Single	SC-79	0.10	0.6
MAVR-001340-12790T	Single	SC-79	0.10	0.6
MAVR-001350-12790T	Single	SC-79	0.10	0.6
MAVR-001320-11410T	Single	SOD-323	0.11	1.2
MAVR-001330-11410T	Single	SOD-323	0.11	1.2
MAVR-001340-11410T	Single	SOD-323	0.11	1.2
MAVR-001350-11410T	Single	SOD-323	0.11	1.2
MAVR-001320-1146FT	Common Cathode	SC-70 (3L)	0.12	1.3
MAVR-001330-1146FT	Common Cathode	SC-70 (3L)	0.12	1.3
MAVR-001340-1146FT	Common Cathode	SC-70 (3L)	0.12	1.3
MAVR-001350-1146FT	Common Cathode	SC-70 (3L)	0.12	1.3

^{*} Restrictions on Hazardous Substances, European Union Directive 2011/65/EU.



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Electrical Specifications @ T_A = +25°C Breakdown Voltage @ I_R = 10 μ A, V_b = 12 V Minimum Reverse Leakage Current @ V_R =10 V, I_R = 100 nA Maximum

	C _T (pF)				Capacitance Ratio	Rs	(Ω)
Part No. ¹	V _R = 0.5 V			V _R = 4.0 V	C _T 0.5 / C _T 3.0	V _R = 2.0 V	
	Min.	Nom.	Max.	Тур.	Тур.	Тур.	Max.
MAVR-001320-xxxxxx	48.0	55.0	63.0	17.0	3.37	0.32	0.50
MAVR-001330-xxxxx	22.0	25.0	30.0	7.80	3.31	0.45	0.70
MAVR-001340-xxxxx	15.0	18.0	21.0	5.20	3.40	0.57	0.85
MAVR-001350-xxxxx	9.5	11.0	13.5	3.60	3.20	0.78	1.00

^{1.} The prefix defines package style, configuration and packaging information. Contact representative for complete part identification.

Absolute Maximum Ratings^{4,5}

@ T_A=+25°C (Unless Otherwise Noted)

Parameter	Absolute Maximum		
Reverse Voltage	12 V		
Forward Current	50 mA		
Operating Temperature	-55°C to +125°C		
Storage Temperature	-55°C to +125°C		

^{4.} Operation of this device above any one of these parameters may cause permanent damage.

^{2.} Capacitance @ 1 MHz

^{3.} Series Resistance @ 100 MHz

^{5.} Please refer to application note M538 for surface mounting instructions.



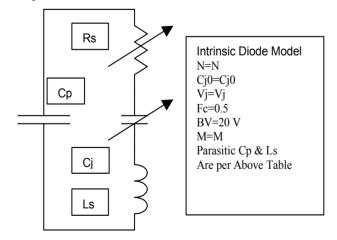
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Typical Capacitance Values

V _R (V)	MAVR-001320	MAVR-001330	MAVR-001340	MAVR-001350
	C _T (pF)	C _T (pF)	C _T (pF)	C _T (pF)
0.5	55.45	25.4	17.7	11.4
1.0	45.0	20.7	14.4	9.3
1.5	36.3	16.8	11.7	7.6
2.0	28.3	13.2	9.2	5.9
2.5	21.2	10.1	7.0	4.5
3.0	16.4	7.9	5.4	3.4
3.5	13.3	6.4	4.4	2.9
4.0	11.4	5.5	3.8	2.5
4.5	10.0	4.8	3.3	2.2
5.0	9.1	4.4	3.0	2.0

Spice Model



Part Number	N	CJ₀ (pF)	(V)	M
MAVR-001320	1.1	71.5	20.35	13.21
MAVR-001330	1.1	32.8	20.91	13.72
MAVR-001340	1.1	22.7	22.32	14.72
MAVR-001350	1.1	14.3	25.52	15.87

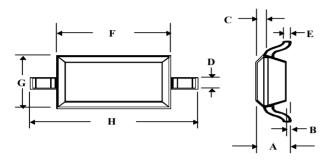


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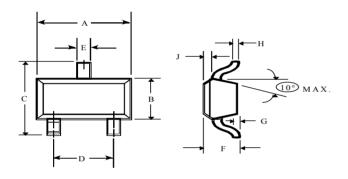
Case Styles

SOD-323 (Case Style 1141)



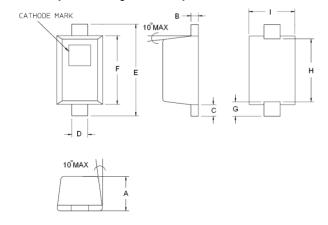
Dim.	Inc	hes	Millimeters		
	Min.	Max.	Min.	Max.	
Α		0.043	_	1.10	
В		0.004	_	0.10	
С		0.008	_	0.20	
D	0.010	0.016	0.25	0.41	
Е	0.003	0.006	0.07	0.15	
F	0.063	0.075	1.60	1.90	
G	0.045	0.057	1.14	1.45	
Н	0.091	0.106	2.30	2.70	

SC-70, 3 lead (Case Style 1146)



Dim.	Inc	hes	Millimeters		
	Min.	Max.	Min.	Max.	
Α	0.071	0.087	1.80	2.21	
В	0.045	0.053	1.14	1.35	
С	0.071	0.094	1.80	2.39	
D	0.047	0.057	1.19	1.45	
Е	0.010	0.016	0.25	0.41	
F	0.031	0.039	0.79	1.00	
G	0.000	0.004	0.00	0.10	
Н	0.004	0.007	0.10	0.18	
J	0.004	0.010	0.10	0.25	

SC-79 (Case Style 1279)



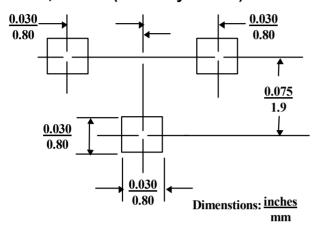
Dim.	Inc	hes	Millimeters		
	Min.	Max.	Min.	Max.	
Α	0.0197	0.0276	0.50	0.70	
В	0.003	0.008	0.07	0.20	
С	0.006	0.010	0.15	0.25	
D	0.010	0.014	0.25	0.35	
Е	0.059	0.067	1.50	1.70	
F	0.043	0.051	1.09	1.30	
G	0.0098 nominal		0.250 r	nominal	
Н	0.0433 nominal		1.10 n	ominal	
I	0.027	0.035	0.68	0.89	



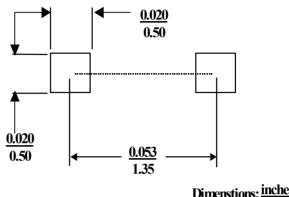
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SC-70, 3 Lead (Case Style 1146)

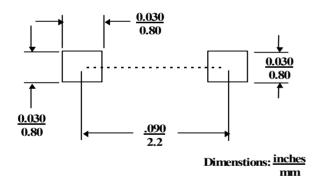


SC-79 (Case Style 1279)



Dimenstions: inches

SOD-323 (Case Style 1141)



Mounting Information

illustration indicates the recommended mounting pad configuration for the SC-79, SC-70 and SOD-323 packages. Solder paste containing flux should be screened onto the pads to a thickness of 0.005- 0.007 inches. The plastic package is placed in position, firmly adhering to the solder

Permanent attachment is performed by a reflow soldering procedure during which the temperature does not exceed +260°C.

Please refer to Application Note M538 for surface mounting instructions.

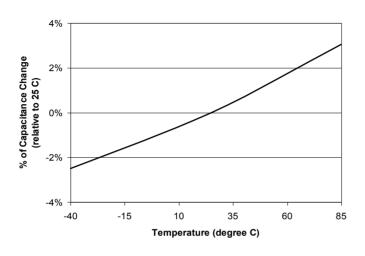


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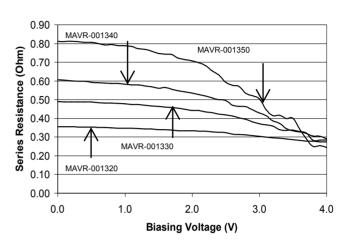
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Typical Performance Curves

Typical Capacitance Change vs. Temperature



Series Resistance vs Biasing Voltage*



Typical Capacitance vs. Biasing Voltage

